



MMDT440

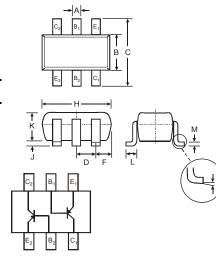
DUAL PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching •
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability • Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C •
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K2T See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.006 grams (approximate)



SOT-363									
Dim	Min	Max							
Α	0.10	0.30							
В	1.15	1.35							
С	2.00 2.20								
D	0.65 Nominal								
F	0.30	0.40							
Н	1.80	2.20							
J	—	0.10							
к	0.90	1.00							
L	0.25	0.40							
М	0.10	0.25							
α	0°	8°							
All Din	nensions	in mm							

Maximum Ratings @T_A = 25°C unless otherwise specified

			r			
Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V _{CBO}	-40	V		
Collector-Emitter Voltage		V _{CEO}	-40	V		
Emitter-Base Voltage		V _{EBO}	-5.0	V		
Collector Current - Continuous	(Note 1)	lc	-600	mA		
Power Dissipation	(Note 1, 2)	Pd	200	mW		
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ extsf{ heta}JA}$	625	°C/W		
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C		

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Maximum combined dissipation. 2.

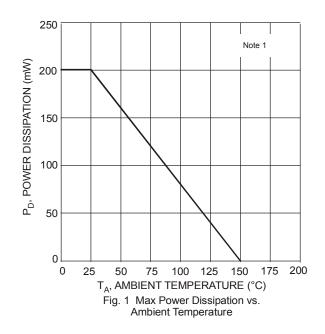
No purposefully added lead. 3.

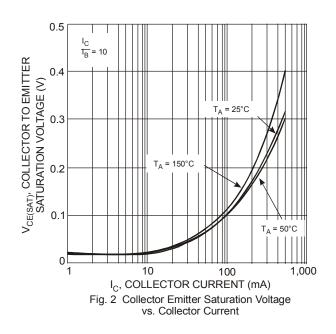
Dio bar posterially data fails.
Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



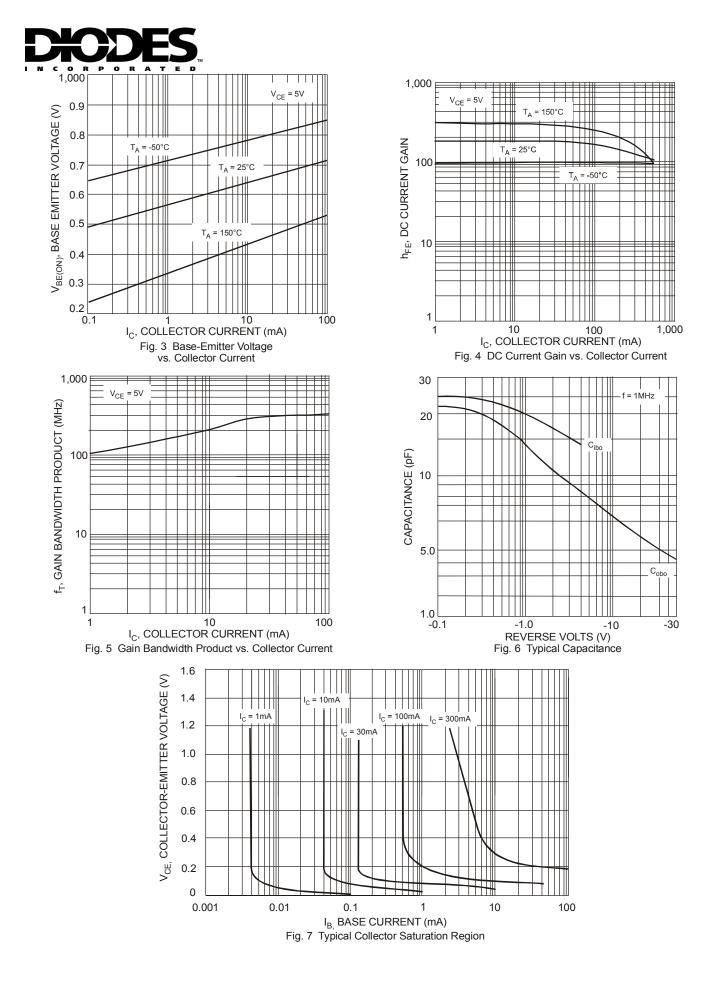
Electrical Characteristics @T _A = 25°C unless otherwise specified								
Characteristic	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 6)								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$			
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	$I_{\rm C}$ = -1.0mA, $I_{\rm B}$ = 0			
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_{\rm E} = -100 \mu A, I_{\rm C} = 0$			
Collector Cutoff Current	I _{CEX}	_	-100	nA	V_{CE} = -35V, $V_{EB(OFF)}$ = -0.4V			
Base Cutoff Current	I _{BL}	_	-100	nA	V_{CE} = -35V, $V_{EB(OFF)}$ = -0.4V			
ON CHARACTERISTICS (Note 6)			-					
DC Current Gain	h _{FE}	30 60 100 100 20	 300 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} &= -1.0 V \\ I_{C} &= -1.0 m A, \ V_{CE} &= -1.0 V \\ I_{C} &= -10 m A, \ V_{CE} &= -1.0 V \\ I_{C} &= -150 m A, \ V_{CE} &= -2.0 V \\ I_{C} &= -500 m A, \ V_{CE} &= -2.0 V \end{split}$			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.40 -0.75	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA			
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.75	-0.95 -1.30	v	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA			
SMALL SIGNAL CHARACTERISTICS			-					
Output Capacitance	C _{cb}	_	8.5	pF	V_{CB} = -10V, f = 1.0MHz, I _E = 0			
Input Capacitance	Ceb	_	30	pF	V_{EB} = -0.5V, f = 1.0MHz, I _C = 0			
Input Impedance	h _{ie}	1.5	15	kΩ				
Voltage Feedback Ratio	h _{re}	0.1	8.0	x 10 ⁻⁴	V _{CE} = -10V, I _C = -1.0mA,			
Small Signal Current Gain	h _{fe}	60	500		f = 1.0kHz			
Output Admittance	h _{oe}	1.0	100	μS				
Current Gain-Bandwidth Product	f _T	200	—	MHz	V _{CE} = -10V, I _C = -20mA, f = 100MHz			
SWITCHING CHARACTERISTICS								
Delay Time	t _d		15	ns	V _{CC} = -30V, I _C = -150mA,			
Rise Time	t _r	_	20	ns	$V_{BE(off)} = -2.0V, I_{B1} = -15mA$			
Storage Time	ts	_	225	ns	V _{CC} = -30V, I _C = -150mA,			
Fall Time	t _f	_	30	ns	$I_{B1} = I_{B2} = -15 \text{mA}$			

Notes: 6. Short duration pulse test used to minimize self-heating effect.





2 of 4 www.diodes.com



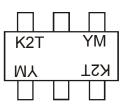


Ordering Information (Note 7)

Device	Packaging	Shipping				
MMDT4403-7-F	SOT-363	3000/Tape & Reel				

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K2T = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
Month	Jan	Feb)	Mar	Apr	Мау	Ju	n	Jul	Aug	Sep	Oc	t I	lov	Dec
Code	4	2		2	4	5	6		7	0	0	0		Ν	Р

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.